

## TOSHIBA RF POWER AMPLIFIER MODULE

### S-AU35AVL, S-AU35AL, S-AU35AH, S-AU35AVH, S-AU35ASH

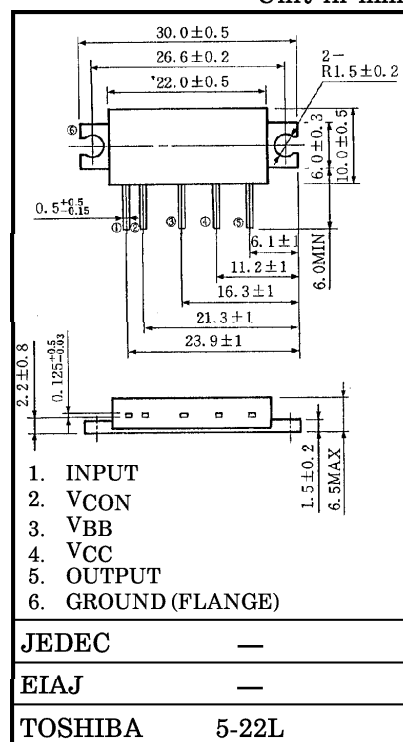
UHF POWER AMPLIFIER MODULE

Unit in mm

- S-AU35AVL : f=360~380MHz
- S-AU35AL : f=400~430MHz
- S-AU35AH : f=450~470MHz
- S-AU35AVH : f=470~490MHz
- S-AU35ASH : f=490~512MHz

#### MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
DC Supply Voltage	V <sub>CC</sub>	11	V
DC Supply Voltage	V <sub>CON</sub>	10	V
DC Supply Voltage	V <sub>BB</sub>	6	A
Input Power	P <sub>i</sub>	400	mW
Operating Case Temperature Range	T <sub>c (opr)</sub>	-30~100	°C
Storage Temperature Range	T <sub>stg</sub>	-40~110	°C



Weight : 3.5g

#### ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Frequency Range	f <sub>range</sub>	—	360	—	512	MHz
Output Power	P <sub>o</sub>	P <sub>i</sub> = 150mW V <sub>CC</sub> = V <sub>CON</sub> = 7.5V, V <sub>BB</sub> = 5V Z <sub>G</sub> = Z <sub>L</sub> = 50Ω	2.6	—	—	W
Power Gain	G <sub>p</sub>		12.3	—	—	dB
Total Efficiency	η <sub>T</sub>		35	—	—	%
Input VSWR	VSWR <sub>in</sub>		—	1.5	2.5	—
Harmonics	HRM		—	—	-20	dB
Load Mismatch	—	V <sub>CC</sub> = V <sub>CON</sub> = 9V V <sub>BB</sub> = 5V P <sub>i</sub> = 200mW VSWR load 20 : 1 all phase	No Degradation			—
Stability	—	V <sub>CC</sub> = 6~9V, V <sub>CON</sub> = 0~9V V <sub>BB</sub> = 5V, V <sub>CON</sub> ≤ V <sub>CC</sub> P <sub>i</sub> = 150mW VSWR load 6 : 1 all phase	All spurious output than 60dB below desired signal			—

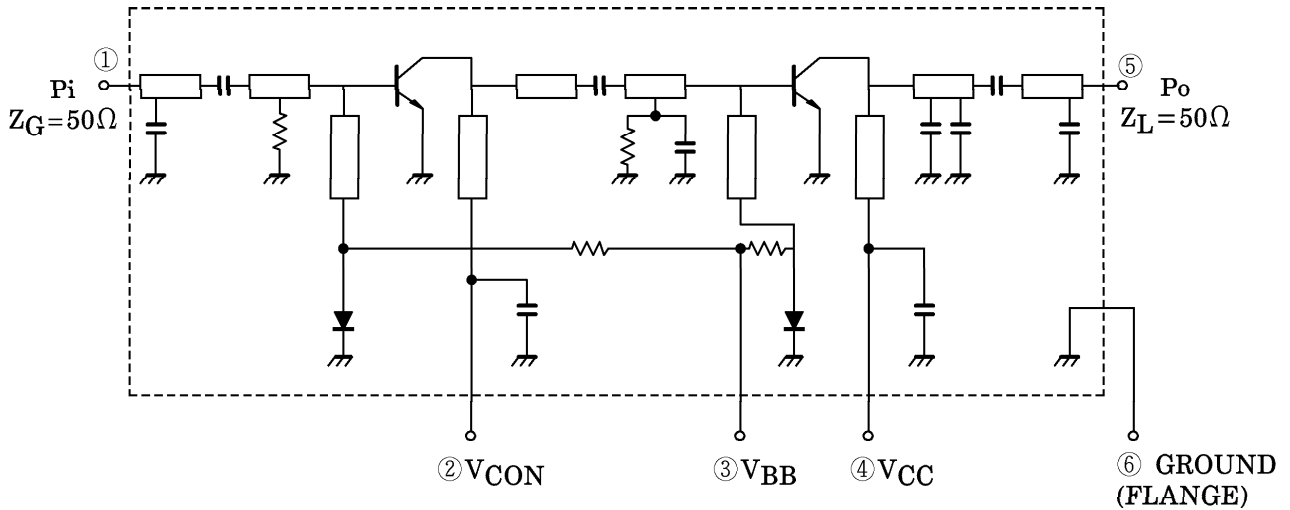
#### CAUTION

- This product has intersetting cap. Please pay attention for exceeding stress and foreign matter in your application. And not to take away the cap.
- Do not intermingle with normal industrial or domestic waste.

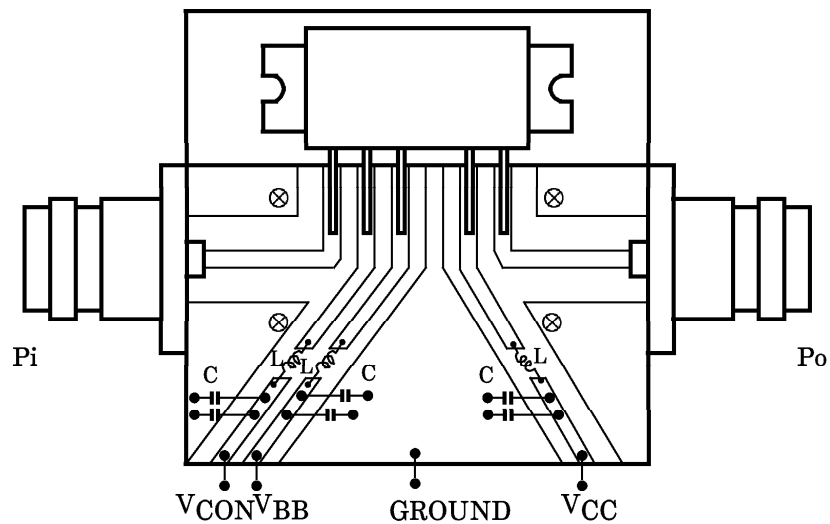
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● TOSHIBA is continually working to improve the quality and the reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to observe standards of safety, and to avoid situations in which a malfunction or failure of a TOSHIBA product could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent products specifications. Also, please keep in mind the precautions and conditions set forth in the TOSHIBA Semiconductor Reliability Handbook.

SCHEMATIC



TEST FIXTURE

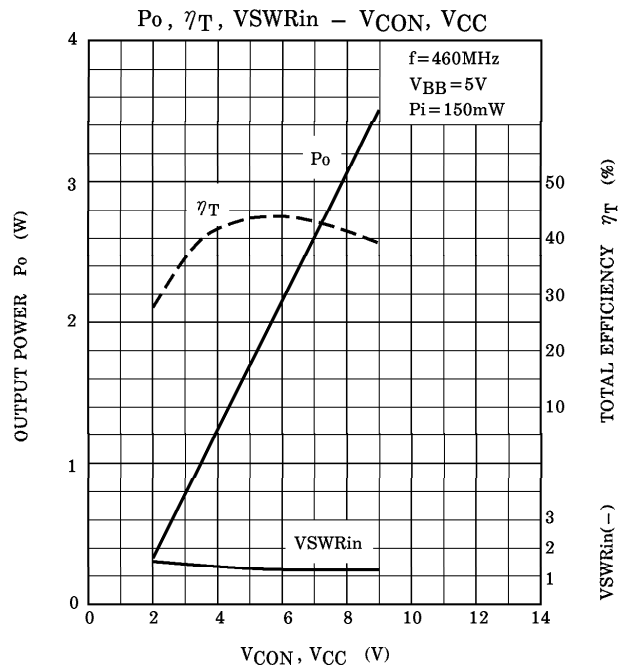
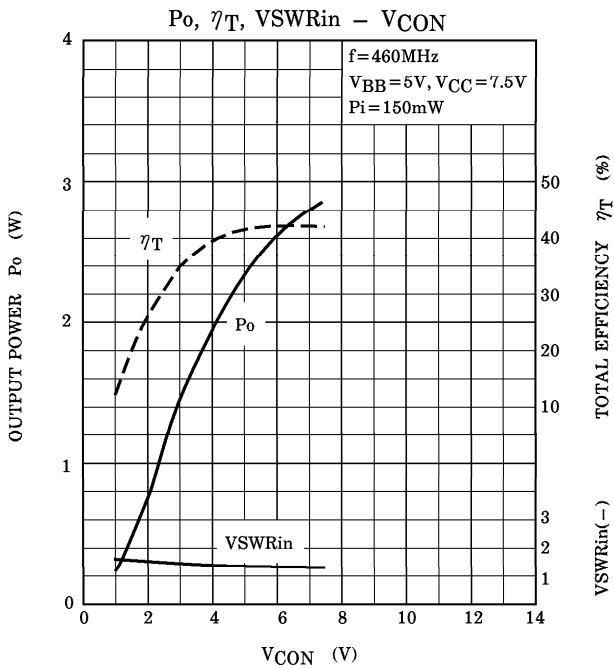
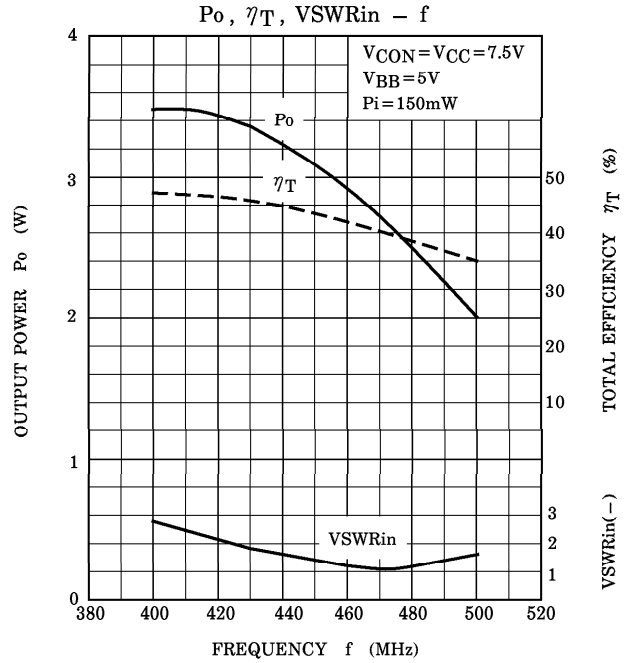
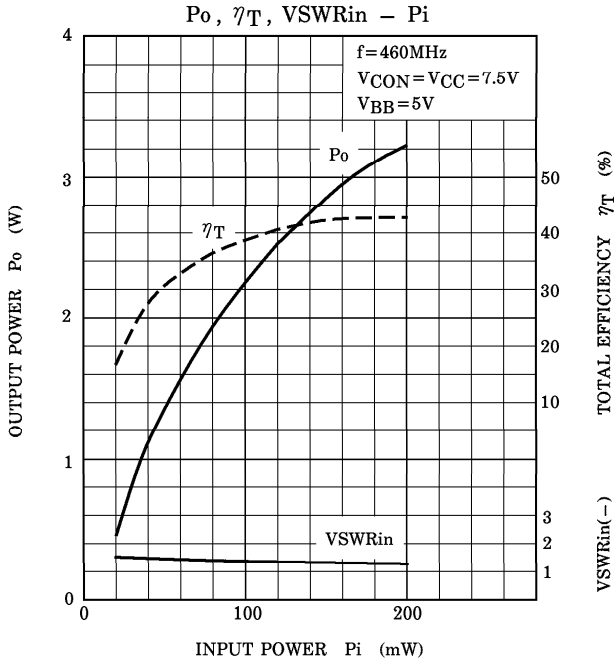


C : 22000pF, 10 $\mu$ F PARALLEL  
 L :  $\phi$ 0.5 ENAMEL WIRE 3ID, 5T

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TYPICAL PERFORMANCE CURVES  
(S-AU35AH)



**CAUTION**

These are only typical curves and devices are not necessarily guaranteed at these curves.